

On the sample size dependence of the critical current density in MgB_2 superconductors

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Sample size dependent critical current density has been observed in magnesium diboride superconductors. At high fields, larger samples provide higher critical current densities, while at low fields, larger samples give rise to lower critical current densities. The explanation for this surprising result is proposed in this study based on the electric field generated in the superconductors. The dependence of the current density on the sample size has been derived as a power law j / R^{1-n} (n is the n factor characterizing $E - j$ curve $E = E_c (j - j_c)^n$). This dependence provides one with a new method to derive the n factor and can also be used to determine the dependence of the activation energy on the current density.

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It has been reported that the critical current density derived from magnetic measurement in the magnesium diboride superconductors depends on the sample size [1, 2]. Usually a larger sample results in a higher critical current density at high fields. If this is a true intrinsic property of this new superconductor, it would be advantageous to use this superconductors in large scale applications. As far as we know, such a phenomenon has not been observed in either high temperature or low temperature superconductors. Explanations have been proposed to account for this observation [1, 2]. Jin et al. [2] measured the relaxation of cylindrical magnesium diboride superconductors of different lengths and found that the activation energy depends linearly on the length of the sample up to 1 mm and saturates after that. The authors suggested that the vortices in the magnesium diboride superconductors are quite rigid at small sample lengths and break into segments as the sample length reaches the collective pinning length L_c ($\frac{2}{3} \phi_0^2 = \frac{1}{2} \mu_0^2$), with ϕ_0 the basic energy scale, λ the coherence length, and a a parameter of disorder strength. However, their proposal cannot explain the higher critical current density for smaller samples at low fields. Horvat et al. [1] proposed that different coupling between the superconducting grains at different length scales is responsible for the sample size dependent critical current density. However, this explanation is quite qualitative and not conclusive.

It is very important to clarify this problem. On the one hand, we need to understand the underlying mechanism governing this dependence in order to see whether we can further improve the critical current density by increasing the sample size and to understand why this phenomenon has not been reported in high temperature or low temperature superconductors. On the other hand, we need a standard to compare the current density of magnesium diboride superconductors fabricated by different techniques. In this paper, we propose an explanation for

this observation based on the electric field generated in the superconductors during a hysteresis loop measurement.

The samples used in this study are all in the shape of rectangular rods cut from a MgB_2 pellet. The sample preparation can be found elsewhere [3]. In order to eliminate any geometric effects on the critical current density, the pellet was cut into a series of samples with constant size ratio $a : b : c$. Seven samples are used in this study with dimensions of $a \times b \times c$ (mm³): 1.07 × 3.27 × 7.15, 0.7 × 2.12 × 4.65, 0.57 × 1.68 × 3.64, 0.46 × 1.34 × 2.92, 0.36 × 1.08 × 2.29, 0.29 × 0.85 × 1.87, 0.24 × 0.68 × 1.42 mm³. The critical current density is derived from magnetic hysteresis loop measurements by means of a Quantum Design PPM S (Physical Property Measurement system) magnetometer with a sweep rate of 50 Oe/s. The measurements are performed with the applied field parallel to the longest direction of the sample (c axis). The critical current density in full penetration can be estimated using the critical state model as: $j = 20 \text{ M} / (a(1 - a/3b))$, where M is the width of the magnetization hysteresis loop.

Fig. 1 shows the magnetic field dependent critical current densities of all the samples at 5 K and 20 K. The arrows indicate the direction where the sample size increases. Flux jumping is observed for all samples at 5 K, but only for the two largest samples at 20 K. It can be clearly seen from Fig. 1 that at high fields (larger than 3 T) the current density increases systematically as the sample size increases. But the current density tends to be saturated when the sample size is very large. The low field part of Fig. 1 is enlarged in Fig. 2, and again the arrow indicates the direction where the sample size increases. Contrary to what is observed at high fields, the current density decreases as the sample size increases.

In order to explain this observation, we start from the flux creep equation derived from Maxwell's equation r $E = -\partial B / \partial t$ with $E = B \times v$ as discussed by Jirsa et al

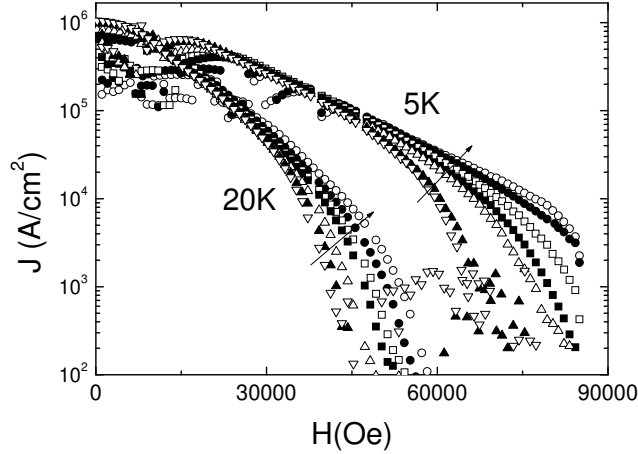


FIG. 1: The magnetic field dependent current density of the MgB_2 samples at 5 K and 20 K. The arrows indicate the direction of increasing sample size.

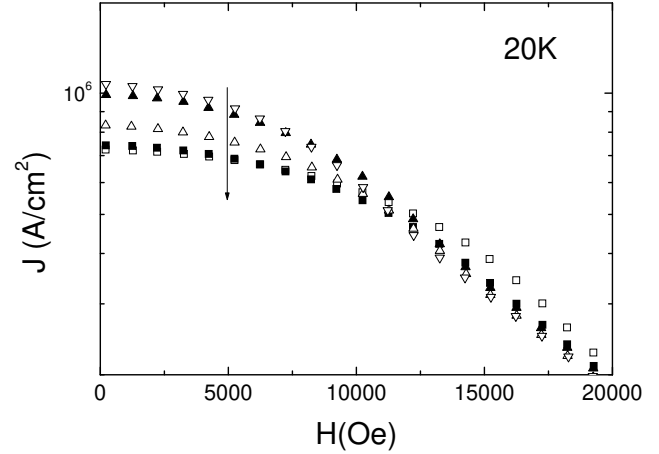


FIG. 2: The magnetic field dependent current density of the MgB_2 samples at low magnetic field for 5 K and 20 K. The arrows indicate the direction of increasing sample size.

[4] and Schnack et al. [5],

$$\frac{dM}{dt} = \frac{\mu_0}{\mu_0} \frac{dB_e}{dt} \exp \left[-\frac{U(j)}{kT} \right] \quad (1)$$

The vortex velocity is assumed to be thermally activated, i.e. $v = v_0 \exp[-U(j)/kT]$, where the attempt velocity $v_0 = x_0 \omega_0$ with attempt frequency ω_0 and attempt distance x_0 is the velocity of vortices when $U(j) = 0$ (i.e. $j = j_c$). $U(j)$ is the activation energy and k the Boltzmann constant. The differential susceptibility μ_0 and the geometric factor in Eq. (1) depend on the size and shape of the sample. Here we consider a disk with B_e parallel to its axis, then we have

$$\mu_0 = \frac{2R^3}{3\pi} \\ = \frac{2}{3\pi} R^2$$

where R is the radius of the disk, $\mu_0 R =$ the self-inductance of the disk. Eq. (1) can be solved for $U(j)$ as

$$U(j) = kT \ln \left[\frac{B_e \mu_0}{\mu_0 \frac{dM}{dt} + \mu_0 \frac{dB_e}{dt}} \right] \quad (2)$$

For a hysteresis loop measurement, we usually have $\mu_0 \frac{dM}{dt} \ll \mu_0 \frac{dB_e}{dt}$, and Eq. (2) can then be reduced to

$$U(j) = kT \ln \left[\frac{B_e \mu_0}{\mu_0 \frac{dB_e}{dt}} \right] = kT \ln \left[\frac{2B_e \mu_0}{R B_e} \right] \quad (3)$$

here $B_e = dB_e/dt$. Eq. (3) is simply related to the current-voltage $I-V$ curves (or j versus E curves where

j is the current density and E the electric field) since for a cylinder of radius R , Faraday's law leads to

$$E = \frac{R}{2} \frac{dB_e}{dt} \quad (4)$$

As can be seen from Eq. (4), a larger sample size R will lead to a larger electric field in the sample, and therefore to a larger current density in the sample. This effect is similar to the effect of B_e on the hysteresis loop as has been used in dynamical relaxation measurements [4, 5].

According to Eq. (3), a different $U(j)$ will result in a different dependence of the current density on the sample size. The relaxation results of MgB_2 samples have led to a logarithmic dependence of the activation energy on the current density [6, 7]

$$U(j) = U_0 \log \frac{j_c}{j} \quad (5)$$

where U_0 is the energy scale and j_c the true critical current density at which $U(j_c) = 0$.

Combining Eq. (3) with Eq. (5), we obtain the sample size dependence of the current density as

$$j = j_c R^{1/n} \frac{B_e}{2B_e \mu_0} \quad (6)$$

where $n = U_0 (B_e/T) = kT$. The above analysis can also be applied to a rectangular rod with $R = ab = (a+b)$.

As can be seen from Eq. (6), the current density depends on the sample size as $j \propto R^{1/n}$, therefore the dependence is determined by the exponent n , which is a function of both temperature T and magnetic field B . If n is very large, there will be no sample size dependence as $R^{1/n} \rightarrow 1$, and this might be the reason why no sample

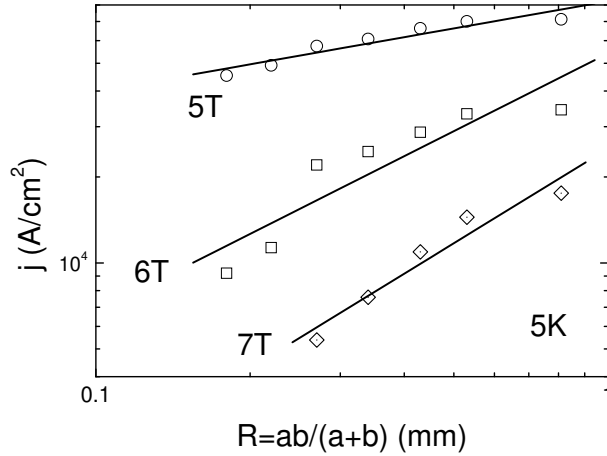


FIG. 3: The sample size dependence of the current density of the MgB_2 samples at 5 T, 6 T and 7 T for 5 K. Solid lines are the best fitting to the linear dependence.

size dependent current density has been reported in low temperature superconductors, characterizing the $E-j$ curve of the superconductors $E = E_c(j=j_c)^n$. Typical n factors in low temperature superconductors vary between 10 and 100 [8]. As an example, magnets which work in the persistent mode without a drift require wires with a high n factor, typically larger than 30 at the highest field [8]. In high temperature superconductors, n values as low as 5 in $\text{NdBa}_2\text{Cu}_3\text{O}_{7-x}$ [9] and $4\text{YBa}_2\text{Cu}_3\text{O}_{7-x}$ [10] at high temperature and high magnetic field have been reported, indicating that a significant sample size dependent current density should be observed. However, weak-links in polycrystalline high temperature superconductors are very serious and prevail against the effects shown in Eq. (6), resulting in a lower critical current density in larger samples.

Although the activation energy was reported to be very high in magnesium diboride at low temperature and low magnetic field, it drops sharply as the applied magnetic field and the temperature are increased [6]. The n factors in MgB_2/Fe tapes and wires have been reported [11, 12] to be around 60 at 4 T, but drop to below 10 at high fields. From the $I-V$ curves of MgB_2 high density bulk samples reported by Pradhan et al. [13], the n factor is derived to be around 1.5 at 26.5 K and 5 T. A similar n factor around 1 has been obtained from $I-V$ curves by Kim et al. [14] at 30 K and 3 T. When the n factor is in this range, the sample size dependence of the current density is expected to appear as seen in Fig. 1. The power law dependence $R^{1/n}$ saturates as R is increased if n is larger than 1, which explains the reported saturation of the current density. Although no saturation is expected at very high temperatures and fields (n may drop below 1), the total current is limited by the irreversibility line

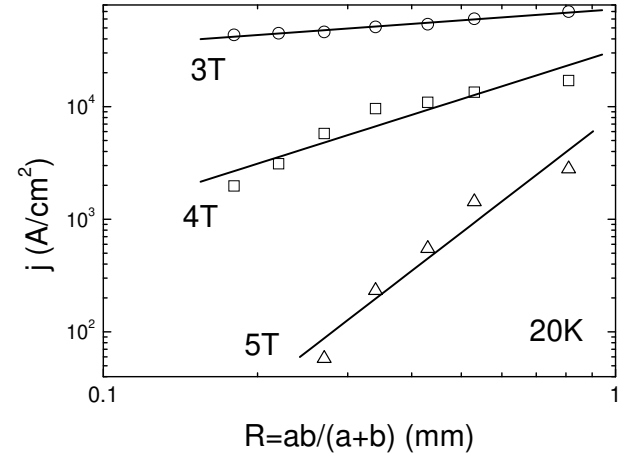


FIG. 4: The sample size dependence of the current density of the MgB_2 samples at 3 T, 4 T and 5 T for 20 K. Solid lines are the best fitting to the linear dependence.

as $B \rightarrow B_{irr}$

Eq. (6) provides us with a new method to determine the n factor $n = U_0(B;T)/kT$ by plotting $\ln j$ versus $\ln R$. The inverse of the slope is just n . This method is applied to the samples used in this study, the results are shown in Fig. 3 and Fig. 4, where $\ln j$ versus $\ln R$ curves at 5 T, 6 T, and 7 T at 5 K, and 3 T, 4 T, 5 T at 20 K are plotted respectively. The solid lines in Fig. 3 and Fig. 4 are the best fittings to the linear dependence between $\ln j$ versus $\ln R$. The derived n factor is shown in Fig. 5 as a function of the applied magnetic field at 5 K and 20 K. The solid lines are only guides to the eyes. This will be a very useful method when the critical current is too high to construct the whole $I-V$ curve to derive the n factor.

On the other hand, as the n factor is very high at low fields [11, 12] (more than 100), a sample size dependence of the current density is not expected ($R^{1/n} \rightarrow 1$). The decreasing current density as the sample size increases might result from the self-field effect. Because larger samples carry larger currents (even if current density is almost the same), generating a larger self-field, this results in a smaller current density. Significant self-field has been observed in high temperature superconductors, especially in tapes with large critical currents [15, 16]. And MgB_2 is expected to show similar behavior. Another possible reason is due to the surface pinning effect [17]. In the presence of both bulk and surface pinning, the magnetization is just the sum of the bulk and surface contributions [18]. However, the surface component is only effective in the fields $H < H_p$, $H_{c1} = \ln$, with the Ginsburg-Landau parameter and H_{c1} the lower critical field [18]. For the rectangular rods in this study, the ratio between the surface area parallel to the applied magnetic

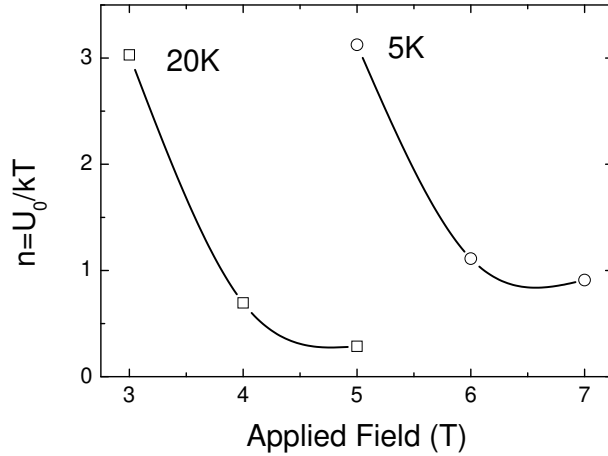


FIG. 5: The n factor as a function of the applied magnetic field of the MgB_2 samples at 5 K and 20 K. The solid lines are only guides to the eyes.

field and the sample volume is $2(ac + bc) = abc = 2R$, indicating a larger surface contribution as the sample size is decreased. This results in a larger current density in a smaller sample. The sample size dependence of the current density at low magnetic fields will be studied in more detail in our forthcoming work.

Another advantage of Eq. (6) is that we can use it to determine the current density dependent activation energy $U(j)$ in the sample. This is because different $U(j)$ relationships lead to different sample size dependences. For example, the linear current density dependent activation energy $U(j) = U_0(1 - j/j_c)$ will give rise to a logarithmic dependence of the current density on the sample size,

$$j = j_c \left[1 + \frac{1}{n} \ln a + \frac{1}{n} \ln \frac{B_e}{2B_{e0}} \right] \quad (7)$$

which is different from the power law dependence shown in Eq. (6). The experimental results shown in Fig. (3) and Fig. (4) indicate that in magnesium diboride superconductors, the activation energy depends logarithmically on the current density (Eq. (5)), rather than having the linear Anderson-Kim type dependence suggested by Jin et al. [2].

In summary, the dependence of the current density on the sample size in magnesium diboride superconductors has been observed and explained in this Letter based on the electric field generated in the superconductors. Starting from the flux creep equation, we have derived an ana-

lytical expression j/R^{1-n} for the sample size dependent current density. We have shown that the sample size dependence of the current density can be used to derive the n factor of MgB_2 samples and can also be used to determine the dependence between the activation energy and the current density.

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